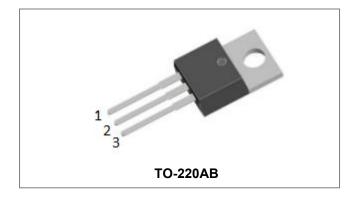


## MBR10150CTU

Technical Data Data Sheet N0753, Rev. A



# MBR10150CTU SCHOTTKY RECTIFIER



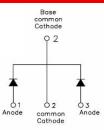
### Features

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

## **Circuit Diagram**



### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	150	V
Average Rectified Forward Current	lf (AV)	50% duty cycle @Tc=100°C, rectangular wave form	5(Per Leg) 10(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	IFSM	8.3ms, Half Sine pulse	138	А

## **Electrical Characteristics:**

Symbol	Condition	Тур.	Max.	Units
V <sub>F1</sub>	@ 5A, Pulse, TJ = 25°C	0.80	0.90	V
V <sub>F2</sub>	@ 5A, Pulse, TJ = 125°C	0.60	0.70	V
I <sub>R1</sub>	$@V_R = rated V_R$ T <sub>J</sub> = 25°C	0.01	1.00	mA
I <sub>R2</sub>	$@V_R = rated V_R$ T <sub>J</sub> = 125°C	0.2	7.0	mA
CT	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25°C, f <sub>SIG</sub> = 1MHz	130	200	pF
Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
dv/dt	-	-	10,000	V/μs
	VF1   VF2   IR1   IR2   CT   LS	$\begin{tabular}{ c c c c c } \hline V_{F1} & @ 5A, Pulse, T_J = 25^\circ C \\ \hline V_{F2} & @ 5A, Pulse, T_J = 125^\circ C \\ \hline & & & & & & & & & & & & & & & & & &$	$\begin{tabular}{ c c c c c c } \hline V_{F1} & @ 5A, Pulse, T_J = 25^\circ C & 0.80 \\ \hline V_{F2} & @ 5A, Pulse, T_J = 125^\circ C & 0.60 \\ \hline & & & & & & & & & & & & & & & & & &$	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$

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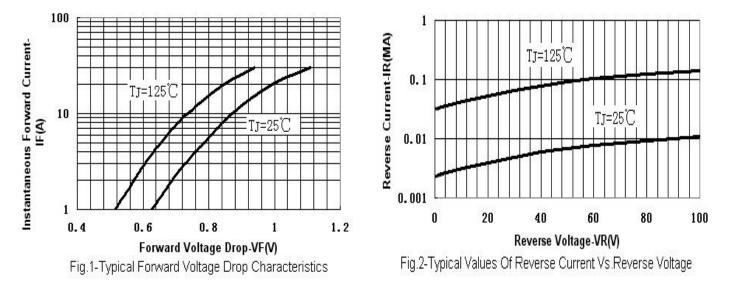
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RoHS 🦻

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	$R_{ ext{ heta}JC}$	DC operation	4.5	°C/W
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			





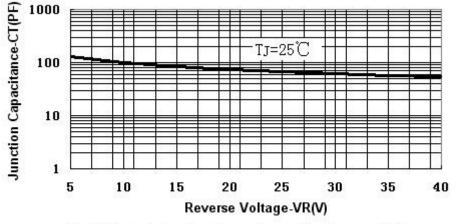


Fig.3-Typical Junction Capacitance Vs.Reverse Voltage

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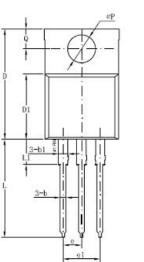
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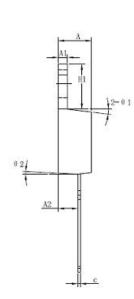
# RoHS 🗭

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### **Mechanical Dimensions TO-220AB**

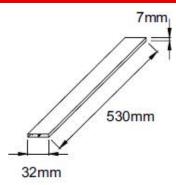




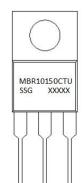


Symbol	Dimensions in millimeters		
	Min	Typical	Max
Α	4.42	4.57	4.72
A1	1.17	1.27	1.37
A2	2.52	2.69	2.89
b	0.71	0.81	0.96
b1	1.17	1.27	1.37
С	0.31	0.38	0.61
D	14.94	15.24	15.54
D1	8.85	9.00	9.15
E	10.01	10.16	10.31
е		2.54	
e1	4.98	5.06	5.18
H1	6.04	6.24	6.44
L	12.7	13.56	13.80
L1	3.56	3.5	3.96
ΦΡ	3.74	3.84	4.04
Q	2.54	2.74	2.94
Θ1		7°	
Θ2		3°	
Θ3		<b>4</b> °	

### **Tube Specification**



## **Marking Diagram**



#### Where XXXXX is YYWWL

MBR = Device Type 10 = Forward Curre

- = Forward Current (10A) = Reverse Voltage(150V)
- = Configuration
- = SSG

150

CTU

SSG

YΥ

ww

L

= Year

= Week

= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## **Ordering Information**

Device	Package	Shipping	
MBR10150CTU	TO-220AB (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging Specification.

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## MBR10150CTU



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